

(FILE 'USPAT' ENTERED AT 15:30:22 ON 04 APR 96)

SET HIGH OFF

L1 25861 S LIQUID CRYSTAL
 L2 3128 S THIN FILM TRANSISTOR# OR TFT#
 L3 2012 S L1 AND L2
 L4 74464 S ETCH?
 SET HIGH ON
 L5 366 S L4 (W) STOPPER#
 L6 71588 S MASK#
 L7 21 S L3 AND L4 AND L5 AND L6
 SET PAGE SCROLL
 L8 0 S PLASMA TAPER AND L3
 L9 0 S PLASMA TAPER? AND L3

FILE 'JPOABS' ENTERED AT 16:04:43 ON 04 APR 96

L10 0 S L7

1. 5,496,752, Mar. 5, 1996, Method of manufacturing thin film transistors in a liquid crystal display apparatus; Yasuhiro Nasu, et al., 437/41, 21, 101 [IMAGE AVAILABLE]
2. 5,496,749, Mar. 5, 1996, Method of manufacturing thin film transistors in a liquid crystal display apparatus; Yasuhiro Nasu, et al., 437/40, 21, 51, 229 [IMAGE AVAILABLE]
- ✓ 3. 5,486,708, Jan. 23, 1996, Light valve device using semiconductive composite substrate; Kunihiro Takahashi, et al., 257/59, 72, 88, 98; 359/59, 68, 79 [IMAGE AVAILABLE]
4. 5,478,766, Dec. 26, 1995, Process for formation of thin film transistor liquid crystal display; Woonyoung Park, et al., 437/40; 148/DIG.105; 437/51, 181, 913 [IMAGE AVAILABLE]
5. 5,473,168, Dec. 5, 1995, Thin film transistor; Katsuhiko Kawai, et al., 257/61, 64, 66, 72 [IMAGE AVAILABLE]
- ✓ 6. 5,472,889, Dec. 5, 1995, Method of manufacturing large-sized thin film transistor liquid crystal display panel; Dong G. Kim, et al., 437/40; 359/59; 437/51, 187 [IMAGE AVAILABLE]
7. 5,468,987, Nov. 21, 1995, Semiconductor device and method for forming the same; Shunpei Yamazaki, et al., 257/412, 308, 406, 411, 640 [IMAGE AVAILABLE]
8. 5,466,620, Nov. 14, 1995, Method for fabricating a liquid crystal display device; Young U. Bang, 437/51, 181, 246 [IMAGE AVAILABLE]
9. 5,462,885, Oct. 31, 1995, Method of manufacturing thin film transistors in a liquid crystal display apparatus; Yasuhiro Nasu, et al., 437/40; 148/DIG.150; 437/21, 51, 229 [IMAGE AVAILABLE]
- ✓ 10. 5,434,433, Jul. 18, 1995, Semiconductor device for a light wave; Hiroaki Takasu, et al., 257/59, 82, 89; 359/58, 59, 82 [IMAGE AVAILABLE]
11. 5,431,773, Jul. 11, 1995, Method of manufacturing semiconductor device; Mitsushi Ikeda, et al., 216/23, 41, 58, 76; 437/228 [IMAGE AVAILABLE]
- ✓ 12. 5,424,857, Jun. 13, 1995, Matrix-type display apparatus with conductor wire interconnecting capacitor electrodes; Hironori Aoki, et al., 359/59, 54, 87 [IMAGE AVAILABLE]
- ✓ 13. 5,418,636, May 23, 1995, Liquid crystal image display apparatus with anodized films of the same thickness and a method of fabricating the same; Kiyohiro Kawasaki, 359/79, 59 [IMAGE AVAILABLE]
14. 5,407,845, Apr. 18, 1995, Method of manufacturing thin film transistors in a liquid crystal display apparatus; Yasuhiro Nasu, et al., 437/40; 148/DIG.150; 437/21, 913 [IMAGE AVAILABLE]
15. 5,403,755, Apr. 4, 1995, Method for fabricating a thin film transistor; Gee S. Chae, 437/21, 41, 909 [IMAGE AVAILABLE]
- ✓ 16. 5,392,143, Feb. 21, 1995, Liquid crystal display having drain and pixel electrodes linkable to a wiring line having a potential; Masahiko

Akiyama, et al., 359/59; 345/93; 359/87 [IMAGE AVAILABLE]

17. 5,355,002, Oct. 11, 1994, Structure of high yield thin film transistors; Bing-Seng Wu, 257/57, 59, 66, 72, 347 [IMAGE AVAILABLE]

✓ 18. 5,349,366, Sep. 20, 1994, Electro-optical device and process for fabricating the same and method of driving the same; Shunpei Yamazaki, et al., 345/92, 206; 359/59 [IMAGE AVAILABLE]

19. 5,347,154, Sep. 13, 1994, Light valve device using semiconductive composite substrate; Kunihiro Takahashi, et al., 257/347, 353; 359/59, 87 [IMAGE AVAILABLE]

20. 5,334,860, Aug. 2, 1994, Panel having thin film element formed thereon; Hideo Naito, 257/59, 60, 927; 359/87 [IMAGE AVAILABLE]

21. 5,334,544, Aug. 2, 1994, Method of making thin film transistors; Tomizo Matsuoka, et al., 437/40; 148/DIG.118; 437/235, 913, 983 [IMAGE AVAILABLE]